NSN 5961-01-102-2868

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View Online at https://aerobasegroup.com/nsn/5961-01-102-2868

Inclosure Material:
Metal
Overall Length:
0.688 inches
Overall Diameter:
0.915 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
1.078 inches
Thread Size:
0.500 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
125.0 collector to base voltage/static/emitter open and 100.0 collector to emitter voltage/static/base open and 10.0 emitter to base voltage,
static, collector open
Current Rating Per Characteristic:
50.00 amperes source cutoff current
Power Rating Per Characteristic:
350.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: npn
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 threaded stud and 3 tab, solder lug

Shelf Life:

Specification Data:

81349-mil-s-19500/380 government specification

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Demilitarization:

No

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